

ISC Silicon NPN Power Transistor

2SC5174

DESCRIPTION

- · Silicon NPN epitaxial type
- · Low Collector Saturation Voltage
- · High transition frequency
- Complementary to 2SA1932
- Good Linearity of h_{FE}
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation



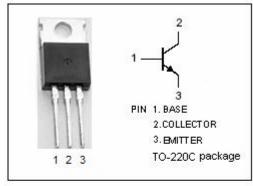
APPLICATIONS

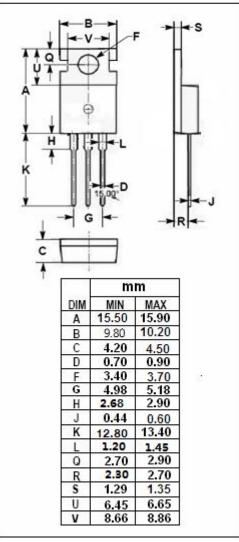
- · Power amplifier applications
- Driver stage amplifier applications



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	230	V	
V _{CEO}	Collector-Emitter Voltage	230	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	1	А	
Ісм	Collector Current-Pulse	3	Α	
I _B	Base Current-Continuous	0.1	Α	
Pc	Collector Power Dissipation @ T _C =25 °C	1.8	W	
TJ	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA ; I _B = 0	230			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			1.0	V
V _{BE(ON)}	Base-Emitter On Voltage	I _C = 500mA; V _{CE} = 5V			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 230V; I _E = 0			1	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			1	μА
h _{FE}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	100		320	
f⊤	Current-Gain—Bandwidth Product	I _E = 0.1A; V _{CE} = 10V		100		MHz
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V;f _{test} = 1.0MHz		20		pF

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